# Onsemi

### Silicon Carbide (SiC) **Schottky Diode** – EliteSiC, 16 A, 650 V, D1, TO-247-2L

### **FFSH1665A**

#### Description

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

#### Features

- Max Junction Temperature 175°C
- Avalanche Rated 81 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery / No Forward Recovery
- This Device is Pb-Free and is RoHS Compliant

#### Applications

- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuits



#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 2 of

| Symbol               | Parameter                                 |                              | FFSH1665A   | Unit |  |
|----------------------|---|------------------------------|-------------|------|--|
| V <sub>RRM</sub>     | Peak Repetitive Reverse Voltage           |                              | 650         | V    |  |
| E <sub>AS</sub>      | Single Pulse Avalanche Energy (Note 1)    |                              | 81          | mJ   |  |
| ١ <sub>F</sub>       | Continuous Rectified Forward Current      | @ Tc < 152°C                 | 16          | А    |  |
|                      |   | @ Tc < 135°C                 | 23          |      |  |
| I <sub>F, Max</sub>  | Non-Repetitive Peak Forward Surge Current | Tc = 25°C, 10 μs             | 1000        | А    |  |
|                      |   | Tc = 150°C, 10 μs            | 900         | А    |  |
| I <sub>F, SM</sub>   | Non-Repetitive Forward Surge Current      | Half-Sine Pulse, tp = 8.3 ms | 90          | А    |  |
| I <sub>F, RM</sub>   | Repetitive Forward Surge Current          | Half-Sine Pulse, tp = 8.3 ms | 50          | А    |  |
| P <sub>tot</sub>     | Power Dissipation                         | Tc = 25°C                    | 161         | W    |  |
|                      |   | Tc = 150°C                   | 27          | W    |  |
| TJ, T <sub>STG</sub> | Operating and Storage Temperature Range   |                              | -55 to +150 | °C   |  |

#### ABSOLUTE MAXIMUM RATINGS (T<sub>C</sub> = 25°C, Unless otherwise specified)

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1.  $E_{AS}$  of 81 mJ is based on starting  $T_J = 25^{\circ}C$ , L = 0.5 mH,  $I_{AS} = 18$  A, V = 50 V. ENC

#### **THERMAL CHARACTERISTICS**

| Symbol          | Parameter                                  |     | Rating   | Unit |
|-----------------|--|-----|----------|------|
| $R_{\theta JC}$ | Thermal Resistance, Junction to Case, Max. |     | 0.93     | °C/W |
| PACKAGE MARKING | AND ORDERING INFORMATION                   | DEC | onservic | )`   |

#### PACKAGE MARKING AND ORDERING INFORMATION

| Part Number | Top Marking Package  | Shipping        |
|-------------|----------------------|-----------------|
| FFSH1665A   | FFSH1665A TO-247-2LD | 30 Units / Tube |
|             |                      |                 |

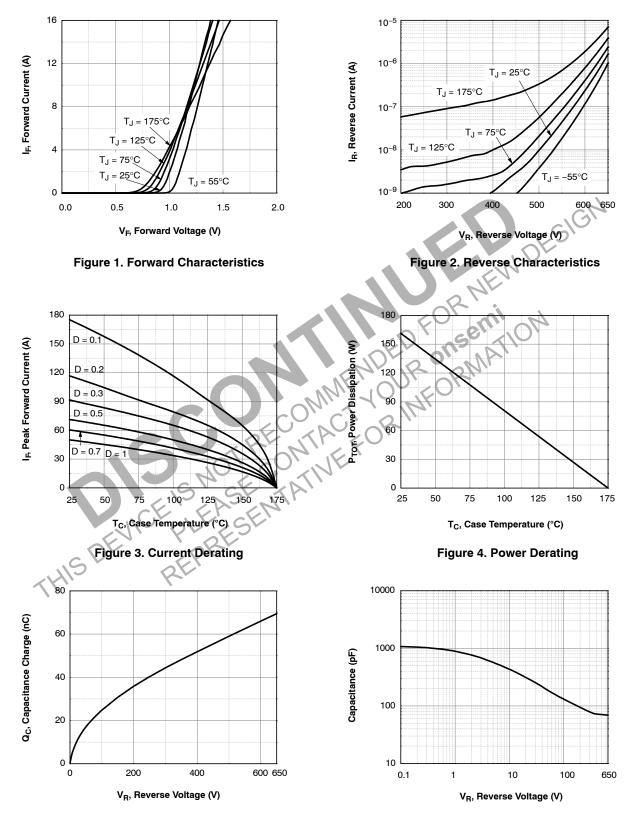
## ELECTRICAL CHARACTERISTICS (T<sub>C</sub> = 25°C unless otherwise noted)

| Symbol         | Parameter               | Test Conditions                     | Min | Тур  | Max  | Unit |
|----------------|-------------------------|-------------------------------------|-----|------|------|------|
| V <sub>F</sub> | Forward Voltage         | l⊧ = 16 A, Tc = 25°C                | -   | 1.50 | 1.75 | V    |
|                | r 15 ASH                | IF = 16 A, Tc = 125°C               | -   | 1.6  | 2.0  |      |
|                | ICE LE SE               | I⊧ = 16 A, Tc = 175°C               | -   | 1.72 | 2.4  |      |
| I <sub>R</sub> | Reverse Current         | VR = 650 V, Tc = 25°C               | -   | -    | 200  | μΑ   |
|                | SVI SEPI                | VR = 650 V, Tc = 125°C              | -   | -    | 400  |      |
|                |                         | VR = 650 V, Tc = 175°C              | -   | -    | 600  |      |
| Q <sub>C</sub> | Total Capacitive Charge | V = 400 V                           | -   | 52   | -    | nC   |
| С              | Total Capacitance       | V <sub>R</sub> = 1 V, f = 100 kHz   | -   | 887  | -    | pF   |
|                |                         | V <sub>R</sub> = 200 V, f = 100 kHz | -   | 95   | -    |      |
|                |                         | VR = 400 V, f = 100 kHz             | -   | 72   | -    |      |

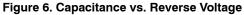
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

#### **TYPICAL CHARACTERISTICS**

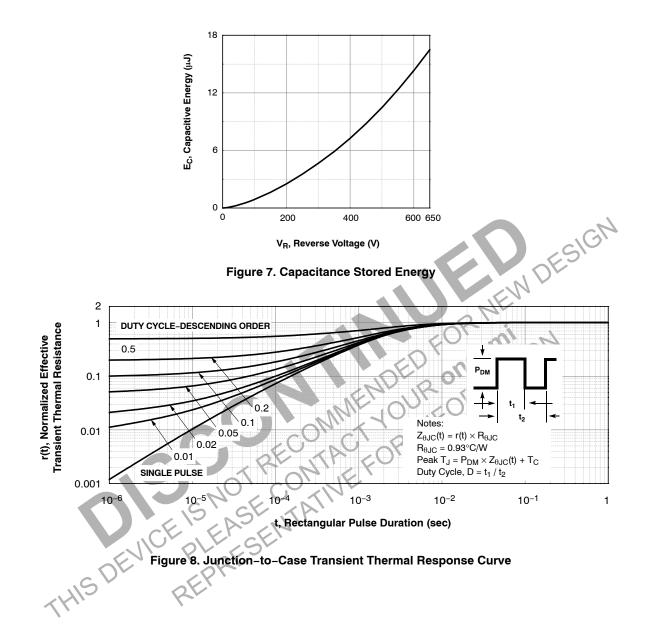
 $(T_J = 25^{\circ}C \text{ UNLESS OTHERWISE NOTED})$ 



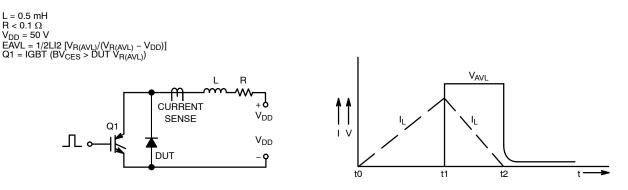




#### **TYPICAL CHARACTERISTICS** (CONTINUED) ( $T_J = 25^{\circ}C$ UNLESS OTHERWISE NOTED)

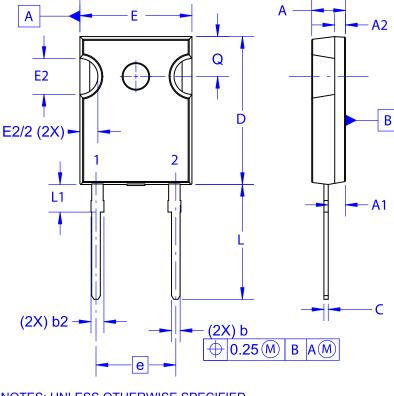


#### **TEST CIRCUIT AND WAVEFORMS**



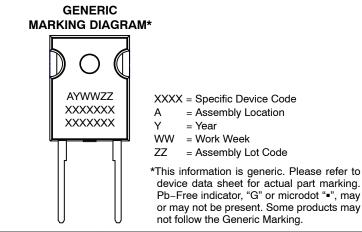


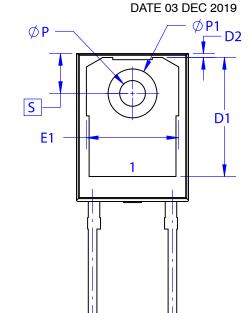
TO-247-2LD CASE 340CL **ISSUE A** 



NOTES: UNLESS OTHERWISE SPECIFIED.

- A. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- C. DRAWING CONFORMS TO ASME Y14.5 2009. D. DIMENSION A1 TO BE MEASURED IN THE REGION DEFINED BY L1.
- E. LEAD FINISH IS UNCONTROLLED IN THE REGION DEFINED BY L1.





|              |       |         | 1     |
|--------------|-------|---------|-------|
|              | MIL   | LIMETER | S     |
| DIM          | MIN   | NOM     | MAX   |
| Α            | 4.58  | 4.70    | 4.82  |
| A1           | 2.29  | 2.40    | 2.66  |
| A2           | 1.30  | 1.50    | 1.70  |
| b            | 1.17  | 1.26    | 1.35  |
| b2           | 1.53  | 1.65    | 1.77  |
| С            | 0.51  | 0.61    | 0.71  |
| D            | 20.32 | 20.57   | 20.82 |
| D1           | 16.37 | 16.57   | 16.77 |
| D2           | 0.51  | 0.93    | 1.35  |
| Е            | 15.37 | 15.62   | 15.87 |
| E1           | 12.81 | ~       | ~     |
| E2           | 4.96  | 5.08    | 5.20  |
| е            | ~     | 11.12   | ~     |
| L            | 15.75 | 16.00   | 16.25 |
| L1           | 3.69  | 3.81    | 3.93  |
| ØР           | 3.51  | 3.58    | 3.65  |
| Ø <b>P</b> 1 | 6.61  | 6.73    | 6.85  |
| Q            | 5.34  | 5.46    | 5.58  |
| S            | 5.34  | 5.46    | 5.58  |
|              |       |         |       |

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|------------------|-------------|---|-------------|--|
| DESCRIPTION:     | TO-247-2LD  |   | PAGE 1 OF 1 |  |

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